

# RF Power Field Effect Transistors

## N-Channel Enhancement-Mode Lateral MOSFETs

Designed for WiMAX base station applications with frequencies up to 3800 MHz. Suitable for WiMAX, WiBro, BWA, and OFDM multicarrier Class AB and Class C amplifier applications.

- Typical WiMAX Performance:  $V_{DD} = 30$  Volts,  $I_{DQ} = 160$  mA,  $P_{out} = 2$  Watts Avg.,  $f = 3400$ -3600 MHz, 802.16d, 64 QAM  $3/4$ , 4 bursts, 7 MHz Channel Bandwidth, Input Signal PAR = 9.5 dB @ 0.01% Probability on CCDF.  
 Power Gain — 15 dB  
 Drain Efficiency — 17%  
 Device Output Signal PAR — 8.5 dB @ 0.01% Probability on CCDF  
 ACPR @ 5.25 MHz Offset — -49 dBc in 0.5 MHz Channel Bandwidth
- Capable of Handling 10:1 VSWR, @ 32 Vdc, 3500 MHz, 10 Watts CW Peak Tuned Output Power
- $P_{out}$  @ 1 dB Compression Point  $\geq 10$  Watts CW

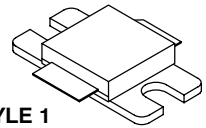
### Features

- Characterized with Series Equivalent Large-Signal Impedance Parameters
- Internally Matched for Ease of Use
- Integrated ESD Protection
- Greater Negative Gate-Source Voltage Range for Improved Class C Operation
- RoHS Compliant
- In Tape and Reel. R3 Suffix = 250 Units per 32 mm, 13 inch Reel.

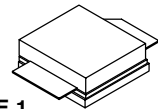
**MRF7S38010HR3**  
**MRF7S38010HSR3**

**3400-3600 MHz, 2 W AVG., 30 V**  
**WiMAX**  
**LATERAL N-CHANNEL**  
**RF POWER MOSFETs**

**CASE 465I-02, STYLE 1**  
**NI-400-240**  
**MRF7S38010HR3**



**CASE 465J-02, STYLE 1**  
**NI-400S-240**  
**MRF7S38010HSR3**



**Table 1. Maximum Ratings**

| Rating                               | Symbol    | Value        | Unit |
|--------------------------------------|-----------|--------------|------|
| Drain-Source Voltage                 | $V_{DS}$  | -0.5, +65    | Vdc  |
| Gate-Source Voltage                  | $V_{GS}$  | -6.0, +10    | Vdc  |
| Operating Voltage                    | $V_{DD}$  | 32, +0       | Vdc  |
| Storage Temperature Range            | $T_{stg}$ | - 65 to +150 | °C   |
| Case Operating Temperature           | $T_C$     | 150          | °C   |
| Operating Junction Temperature (1,2) | $T_J$     | 225          | °C   |

**Table 2. Thermal Characteristics**

| Characteristic  | Symbol          | Value (2,3)  | Unit |
|---|-----------------|--------------|------|
| Thermal Resistance, Junction to Case<br>Case Temperature 80°C, 10 W CW<br>Case Temperature 77°C, 2 W CW | $R_{\theta JC}$ | 2.05<br>2.24 | °C/W |

1. Continuous use at maximum temperature will affect MTTF.
2. MTTF calculator available at <http://www.freescale.com/rf>. Select Tools/Software/Application Software/Calculators to access the MTTF calculators by product.
3. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

**Table 3. ESD Protection Characteristics**

| Test Methodology                      | Class        |
|---------------------------------------|--------------|
| Human Body Model (per JESD22-A114)    | 1C (Minimum) |
| Machine Model (per EIA/JESD22-A115)   | A (Minimum)  |
| Charge Device Model (per JESD22-C101) | IV (Minimum) |

**Table 4. Electrical Characteristics** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**Off Characteristics**

|   |           |   |   |    |                 |
|---|-----------|---|---|----|-----------------|
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 65\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 10 | $\mu\text{Adc}$ |
| Zero Gate Voltage Drain Leakage Current<br>( $V_{DS} = 28\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) | $I_{DSS}$ | — | — | 1  | $\mu\text{Adc}$ |
| Gate-Source Leakage Current<br>( $V_{GS} = 5\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )              | $I_{GSS}$ | — | — | 1  | $\mu\text{Adc}$ |

**On Characteristics**

|   |              |     |      |     |     |
|---|--------------|-----|------|-----|-----|
| Gate Threshold Voltage<br>( $V_{DS} = 10\text{ Vdc}$ , $I_D = 33.5\ \mu\text{Adc}$ )                          | $V_{GS(th)}$ | 1.2 | 2    | 2.7 | Vdc |
| Gate Quiescent Voltage<br>( $V_{DD} = 30\text{ Vdc}$ , $I_D = 160\text{ mAdc}$ , Measured in Functional Test) | $V_{GS(Q)}$  | 2   | 2.7  | 3.5 | Vdc |
| Drain-Source On-Voltage<br>( $V_{GS} = 10\text{ Vdc}$ , $I_D = 335\text{ mAdc}$ )                             | $V_{DS(on)}$ | 0.1 | 0.21 | 0.3 | Vdc |

**Dynamic Characteristics (1)**

|   |           |   |      |   |    |
|---|-----------|---|------|---|----|
| Reverse Transfer Capacitance<br>( $V_{DS} = 28\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ ) | $C_{rss}$ | — | 0.13 | — | pF |
| Output Capacitance<br>( $V_{DS} = 28\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$ )           | $C_{oss}$ | — | 68.5 | — | pF |
| Input Capacitance<br>( $V_{DS} = 28\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz)            | $C_{iss}$ | — | 50.6 | — | pF |

**Functional Tests** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 30\text{ Vdc}$ ,  $I_{DQ} = 160\text{ mA}$ ,  $P_{out} = 2\text{ W Avg.}$ ,  $f = 3400\text{ MHz}$  and  $f = 3600\text{ MHz}$ , WiMAX Signal, 802.16d, 7 MHz Channel Bandwidth, 64 QAM  $^{3/4}$ , 4 Bursts, PAR = 9.5 dB @ 0.01% Probability on CCDF. ACPR measured in 0.5 MHz Channel Bandwidth @  $\pm 5.25\text{ MHz}$  Offset.

|  |          |    |     |     |     |
|--|----------|----|-----|-----|-----|
| Power Gain   | $G_{ps}$ | 13 | 15  | 17  | dB  |
| Drain Efficiency   | $\eta_D$ | 15 | 17  | 30  | %   |
| Output Peak-to-Average Ratio @ 0.01% Probability on CCDF | PAR      | 8  | 8.5 | —   | dB  |
| Adjacent Channel Power Ratio                             | ACPR     | —  | -49 | -46 | dBc |
| Input Return Loss  | IRL      | —  | -12 | -6  | dB  |

1. Part internally matched both on input and output.

(continued)

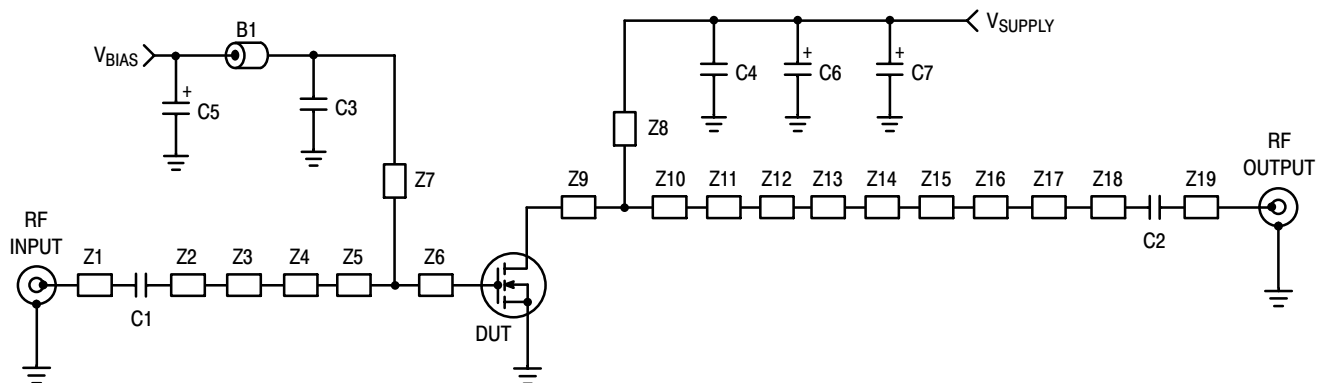
**Table 4. Electrical Characteristics** ( $T_C = 25^\circ\text{C}$  unless otherwise noted) (continued)

| Characteristic  | Symbol | Min | Typ                             | Max | Unit  |
|---|--------|-----|---------------------------------|-----|-------|
| <b>Typical Performances OFDM Signal</b> (In Freescale Test Fixture, 50 ohm system) $V_{DD} = 30\text{ Vdc}$ , $I_{DQ} = 160\text{ mA}$ , $P_{out} = 2\text{ W Avg.}$ , $f = 3400\text{ MHz}$ and $f = 3600\text{ MHz}$ , WiMAX Signal, OFDM Single-Carrier, 7 MHz Channel Bandwidth, 64 QAM $3/4$ , 4 Bursts, PAR = 9.5 dB @ 0.01% Probability on CCDF. |        |     |                                 |     |       |
| Mask System Type G @ $P_{out} = 2\text{ W Avg.}$<br>Point B at 3.5 MHz Offset<br>Point C at 5 MHz Offset<br>Point D at 7.4 MHz Offset<br>Point E at 14 MHz Offset<br>Point F at 17.5 MHz Offset   | Mask   | —   | -26<br>-38<br>-43<br>-60<br>-60 | —   | dBc   |
| Relative Constellation Error @ $P_{out} = 2\text{ W Avg.}$ <sup>(1)</sup>   | RCE    | —   | -33                             | —   | dB    |
| Error Vector Magnitude <sup>(1)</sup><br>(Typical EVM Performance @ $P_{out} = 2\text{ W Avg.}$ with OFDM 802.16d Signal Call)  | EVM    | —   | 2.3                             | —   | % rms |

**Typical Performances** (In Freescale Test Fixture, 50 ohm system)  $V_{DD} = 30\text{ Vdc}$ ,  $I_{DQ} = 160\text{ mA}$ , 3400-3600 MHz Bandwidth

|   |                  |   |       |   |        |
|---|------------------|---|-------|---|--------|
| Video Bandwidth @ 12 W PEP $P_{out}$ where $IM3 = -30\text{ dBc}$<br>(Tone Spacing from 100 kHz to VBW)<br>$\Delta IM3 = IM3 @ \text{VBW frequency} - IM3 @ 100\text{ kHz} < 1\text{ dBc}$ (both sidebands) | VBW              | — | 20    | — | MHz    |
| Gain Flatness in 200 MHz Bandwidth @ $P_{out} = 2\text{ W Avg.}$  | $G_F$            | — | 1.04  | — | dB     |
| Average Deviation from Linear Phase in 200 MHz Bandwidth<br>@ $P_{out} = 10\text{ W CW}$  | $\Phi$           | — | 2.22  | — | °      |
| Average Group Delay @ $P_{out} = 10\text{ W CW}$ , $f = 3500\text{ MHz}$  | Delay            | — | 1.88  | — | ns     |
| Part-to-Part Insertion Phase Variation @ $P_{out} = 10\text{ W CW}$ ,<br>$f = 3500\text{ MHz}$ , Six Sigma Window   | $\Delta\Phi$     | — | 25.9  | — | °      |
| Gain Variation over Temperature<br>(-30°C to +85°C)   | $\Delta G$       | — | 0.025 | — | dB/°C  |
| Output Power Variation over Temperature<br>(-30°C to +85°C)   | $\Delta P_{1dB}$ | — | 0.246 | — | dBm/°C |

1.  $RLE = 20\text{Log}(EVM/100)$



|         |                            |     |  |
|---------|----------------------------|-----|--|
| Z1, Z19 | 0.750" x 0.084" Microstrip | Z11 | 0.032" x 0.166" Microstrip                           |
| Z2      | 0.596" x 0.084" Microstrip | Z12 | 0.124" x 0.538" Microstrip                           |
| Z3      | 0.288" x 0.110" Microstrip | Z13 | 0.099" x 0.341" Microstrip                           |
| Z4      | 0.450" x 0.084" Microstrip | Z14 | 0.220" x 0.166" Microstrip                           |
| Z5      | 0.067" x 0.367" Microstrip | Z15 | 0.063" x 0.240" Microstrip                           |
| Z6      | 0.083" x 0.307" Microstrip | Z16 | 0.085" x 0.340" Microstrip                           |
| Z7      | 0.830" x 0.058" Microstrip | Z17 | 0.037" x 0.340" x 0.257" Taper                       |
| Z8      | 0.567" x 0.128" Microstrip | Z18 | 0.637" x 0.084" Microstrip                           |
| Z9      | 0.116" x 0.367" Microstrip | PCB | CuClad 250GX-0300-55-22, 0.030", $\epsilon_r = 2.55$ |
| Z10     | 0.064" x 0.307" Microstrip |     |  |

**Figure 1. MRF7S38010HR3(HSR3) Test Circuit Schematic**

**Table 5. MRF7S38010HR3(HSR3) Test Circuit Component Designations and Values**

| Part       | Description  | Part Number       | Manufacturer |
|------------|--|-------------------|--------------|
| B1         | 95 $\Omega$ , 100 MHz Long Ferrite Bead, Surface Mount | 2743021447        | Fair-Rite    |
| C1         | 2.2 pF Chip Capacitor                                  | ATC100B2R2JT500XT | ATC          |
| C2         | 2.7 pF Chip Capacitor                                  | ATC100B2R7BT500XT | ATC          |
| C3, C4     | 0.8 pF Chip Capacitors                                 | ATC100B0R8BT500XT | ATC          |
| C5, C6, C7 | 22 $\mu$ F, 35 V Tantalum Capacitors                   | T491X226K035AT    | Kemet        |

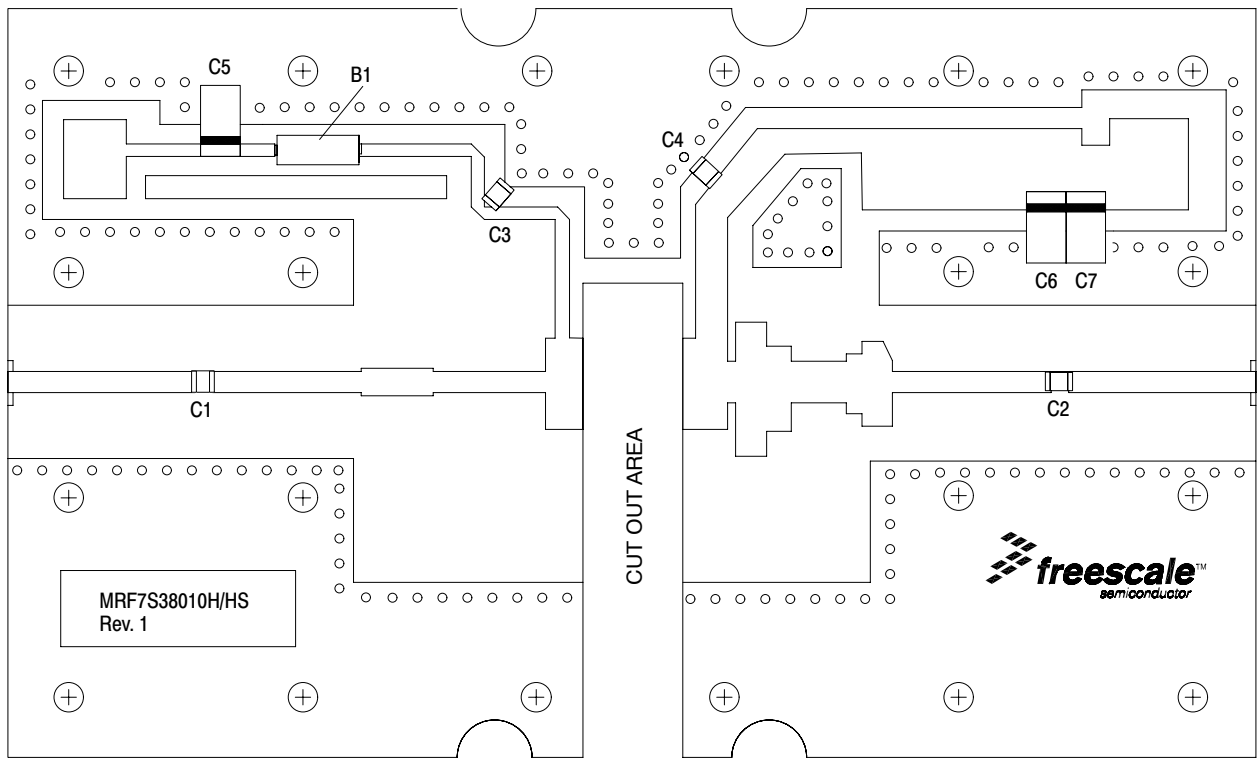


Figure 2. MRF7S38010HR3(HSR3) Test Circuit Component Layout

## TYPICAL CHARACTERISTICS

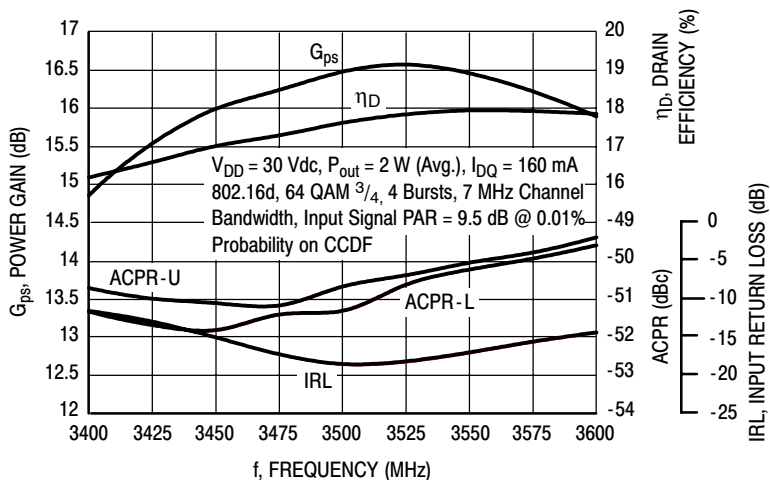


Figure 3. WiMAX Broadband Performance @  $P_{out} = 2$  Watts Avg.

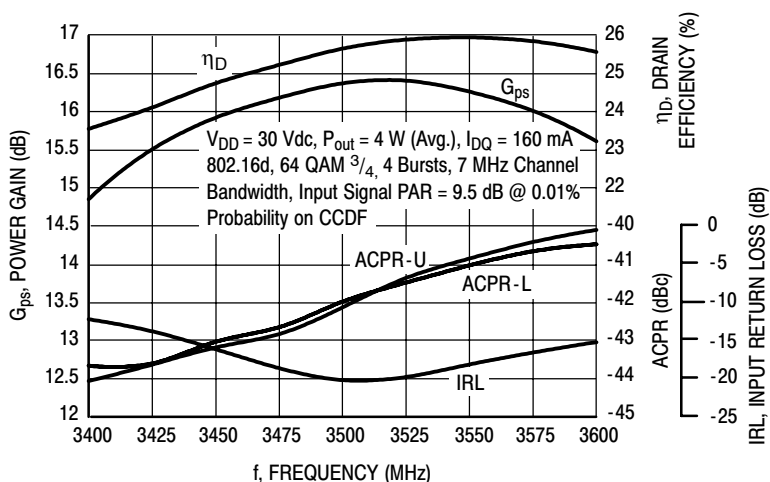


Figure 4. WiMAX Broadband Performance @  $P_{out} = 4$  Watts Avg.

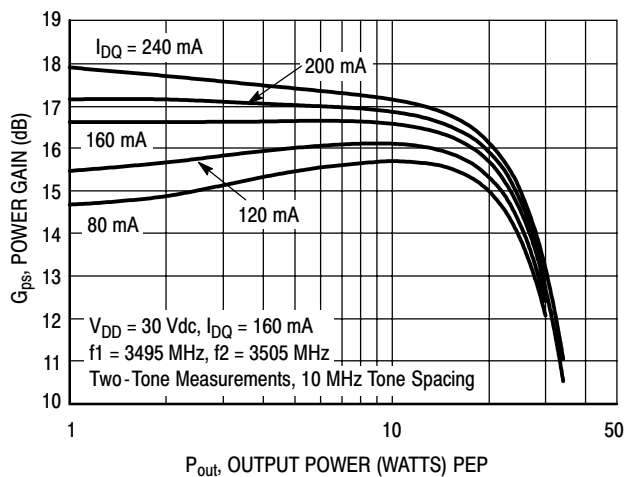


Figure 5. Two-Tone Power Gain versus Output Power

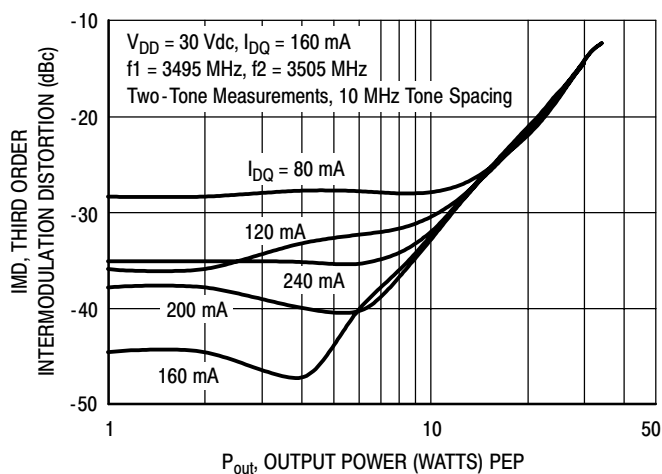


Figure 6. Third Order Intermodulation Distortion versus Output Power

## TYPICAL CHARACTERISTICS

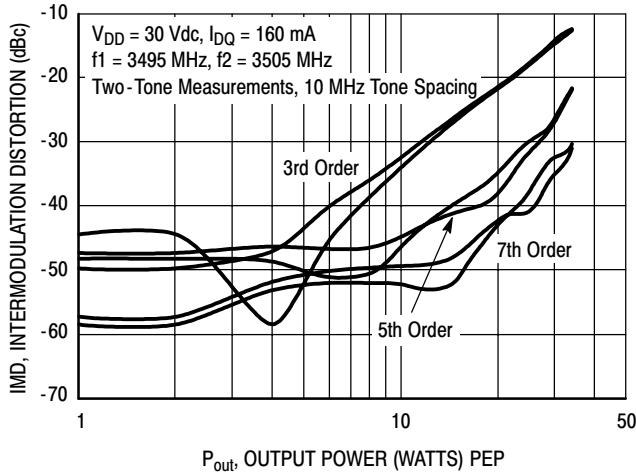


Figure 7. Intermodulation Distortion Products versus Output Power

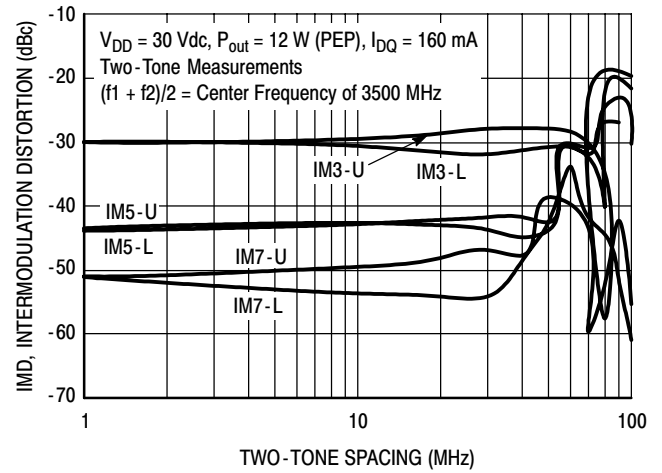


Figure 8. Intermodulation Distortion Products versus Tone Spacing

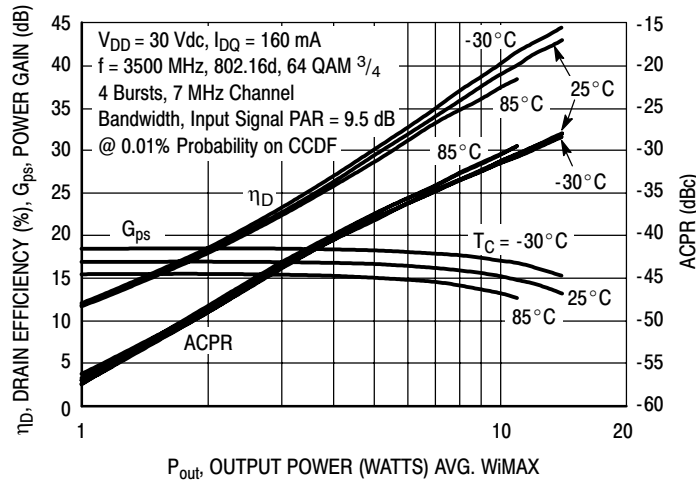


Figure 9. WiMAX, ACPR, Power Gain and Drain Efficiency versus Output Power

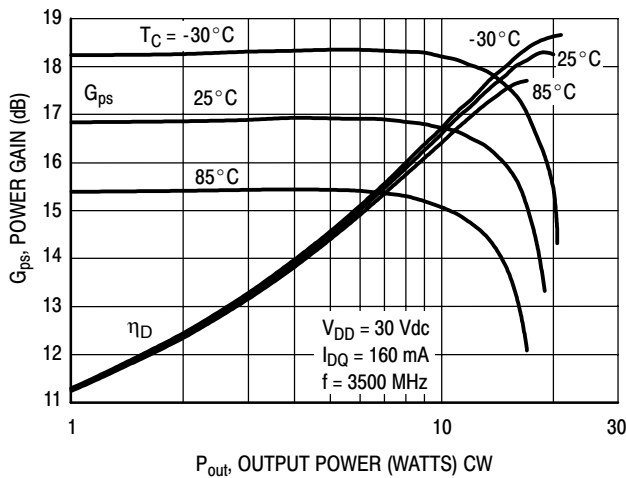


Figure 10. Power Gain and Drain Efficiency versus CW Output Power

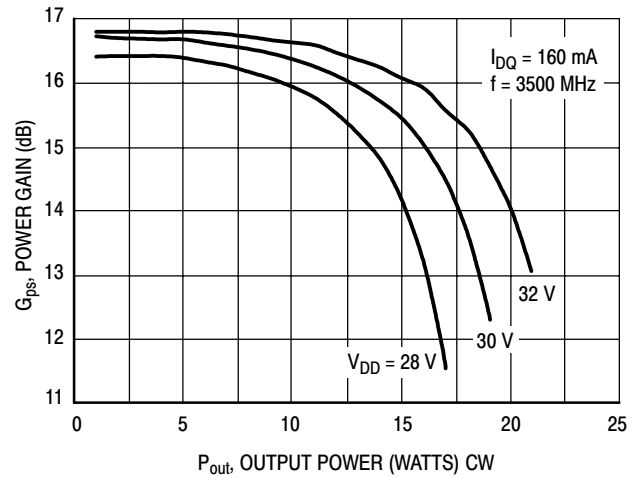
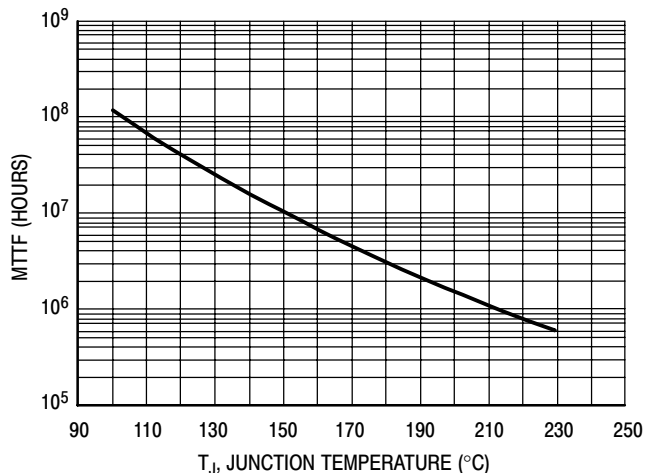


Figure 11. Power Gain versus Output Power

## TYPICAL CHARACTERISTICS

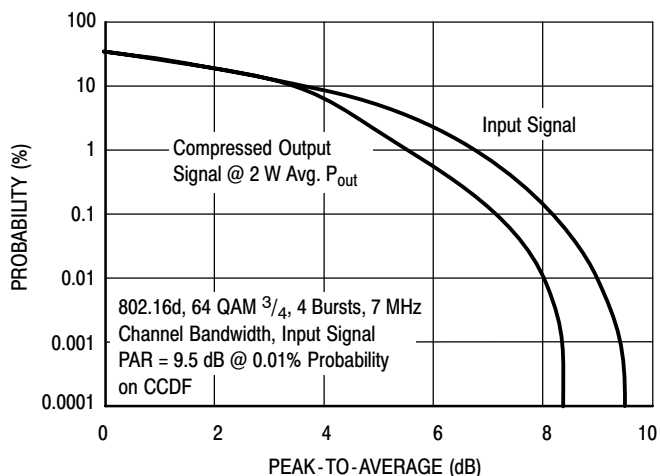


This above graph displays calculated MTTF in hours when the device is operated at  $V_{DD} = 30$  Vdc,  $P_{out} = 2$  W Avg., and  $\eta_D = 17\%$ .

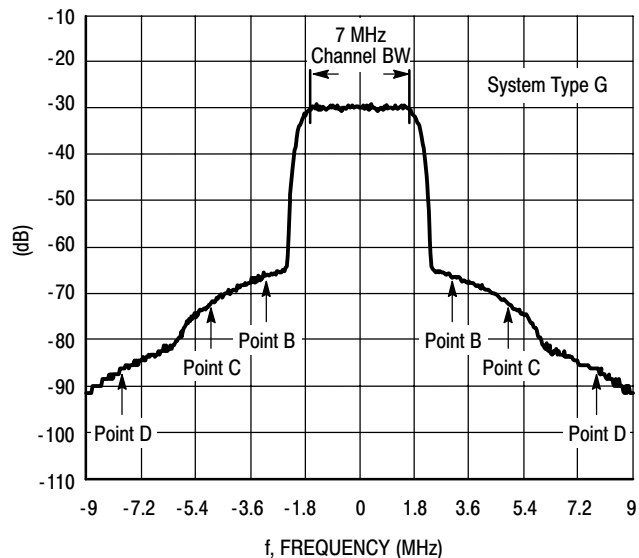
MTTF calculator available at <http://www.freescale.com/rf>. Select Tools/Software/Application Software/Calculators to access the MTTF calculators by product.

**Figure 12. MTTF versus Junction Temperature**

## WIMAX TEST SIGNAL

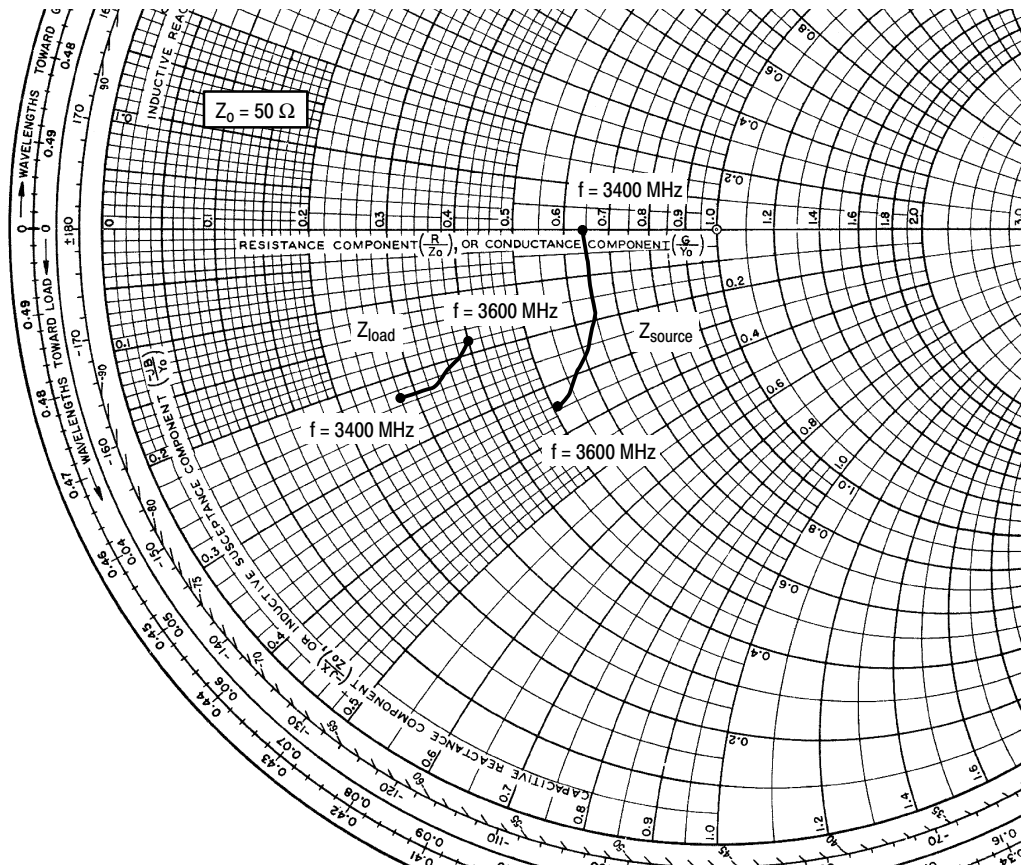


**Figure 13. OFDM 802.16d Test Signal**



**Figure 14. WiMAX Spectrum Mask Specifications**





$V_{DD} = 30 \text{ Vdc}$ ,  $I_{DQ} = 160 \text{ mA}$ ,  $P_{out} = 2 \text{ W Avg.}$

| f<br>MHz | $Z_{source}$<br>$\Omega$ | $Z_{load}$<br>$\Omega$ |
|----------|--------------------------|------------------------|
| 3400     | 31.79 - j0.13            | 13.92 - j11.33         |
| 3425     | 32.46 - j3.62            | 14.61 - j11.40         |
| 3450     | 32.58 - j6.82            | 15.53 - j11.36         |
| 3475     | 32.29 - j9.43            | 16.44 - j11.28         |
| 3500     | 31.32 - j11.63           | 17.25 - j11.07         |
| 3525     | 30.03 - j13.46           | 18.11 - j10.64         |
| 3550     | 28.76 - j15.19           | 18.96 - j10.22         |
| 3575     | 27.24 - j16.25           | 19.60 - j9.68          |
| 3600     | 25.51 - j17.02           | 20.17 - j8.99          |

$Z_{source}$  = Test circuit impedance as measured from gate to ground.

$Z_{load}$  = Test circuit impedance as measured from drain to ground.

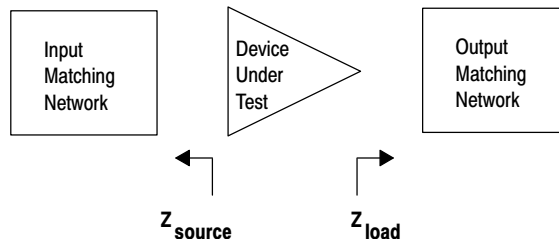
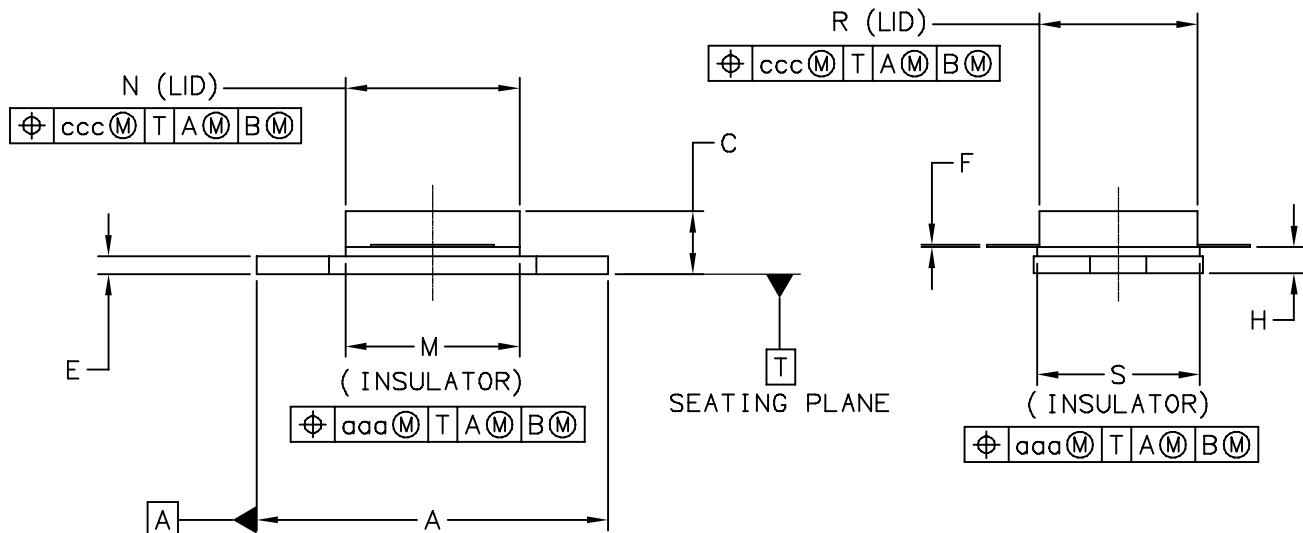
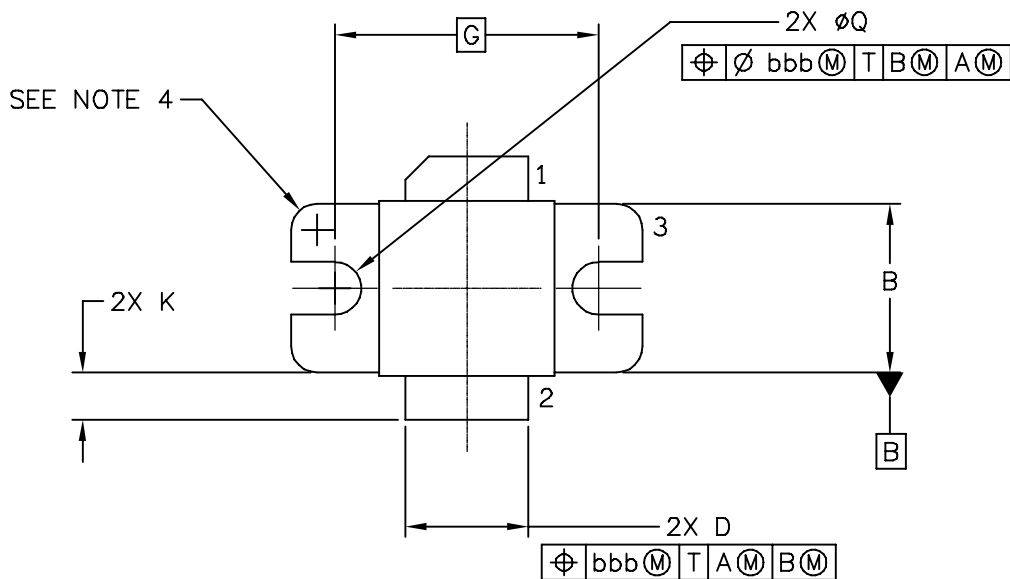


Figure 15. Series Equivalent Source and Load Impedance

**PACKAGE DIMENSIONS**



|   |                           |                            |             |
|---|---------------------------|----------------------------|-------------|
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| TITLE:<br><br>NI-400-240                                | DOCUMENT NO: 98ASA10730D  |                            | REV: B      |
|   | CASE NUMBER: 465I-02      |                            | 09 MAY 2006 |
|   | STANDARD: NON-JEDEC       |                            |             |

NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY.
4. INFORMATION ONLY:  
CORNER BREAK (4X) TO BE .060±.005 (1.52±0.13) RADIUS OR  
.06±.005 (1.52±0.13) x 45° CHAMFER.

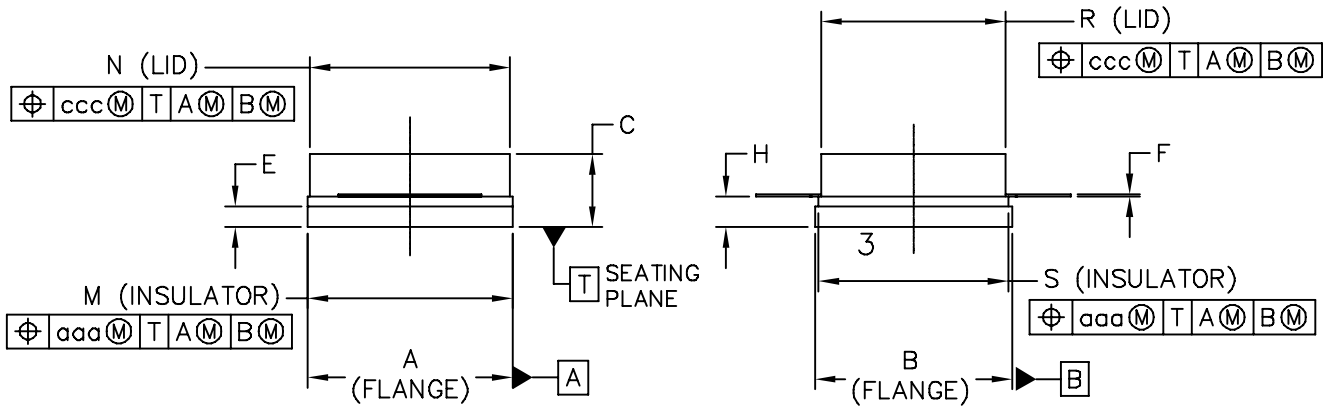
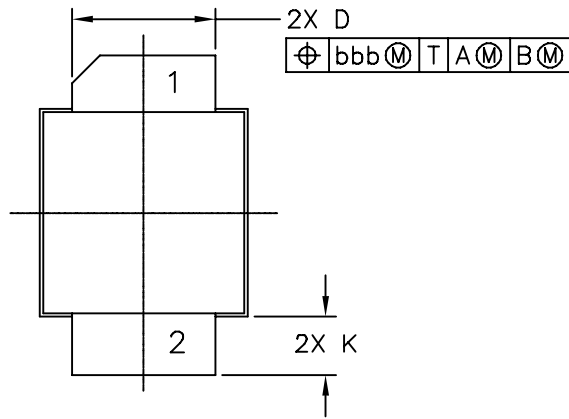
STYLE 1

PIN 1: DRAIN  
PIN 2: GATE  
PIN 3: SOURCE

STYLE 2

PIN 1: GATE  
PIN 2: DRAIN  
PIN 3: SOURCE

| DIM   | INCH     |       | MILLIMETER                |       | DIM                      | INCH                       |      | MILLIMETER  |      |
|---|----------|-------|---------------------------|-------|--------------------------|----------------------------|------|-------------|------|
|   | MIN      | MAX   | MIN                       | MAX   |                          | MIN                        | MAX  | MIN         | MAX  |
| A   | .795     | .805  | 20.19                     | 20.44 | R                        | .355                       | .365 | 9.02        | 9.27 |
| B   | .380     | .390  | 9.65                      | 9.91  | S                        | .365                       | .375 | 9.27        | 9.53 |
| C   | .125     | .163  | 3.17                      | 4.14  |                          |                            |      |             |      |
| D   | .275     | .285  | 6.98                      | 7.24  | aaa                      | .005                       |      | 0.127       |      |
| E   | .035     | .045  | 0.89                      | 1.14  | bbb                      | .010                       |      | 0.254       |      |
| F   | .004     | .006  | 0.10                      | 0.15  | ccc                      | .015                       |      | 0.381       |      |
| G   | .600 BSC |       | 15.24 BSC                 |       |                          |                            |      |             |      |
| H   | .057     | .067  | 1.45                      | 1.70  |                          |                            |      |             |      |
| K   | .0995    | .1295 | 2.53                      | 3.29  |                          |                            |      |             |      |
| M   | .395     | .405  | 10.03                     | 10.29 |                          |                            |      |             |      |
| N   | .385     | .395  | 9.78                      | 10.03 |                          |                            |      |             |      |
| Q   | ∅.120    | ∅.130 | ∅3.05                     | ∅3.30 |                          |                            |      |             |      |
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| TITLE:<br><br>NI-400-240                                |          |       |                           |       | DOCUMENT NO: 98ASA10730D |                            |      | REV: B      |      |
|   |          |       |                           |       | CASE NUMBER: 465I-02     |                            |      | 09 MAY 2006 |      |
|   |          |       |                           |       | STANDARD: NON-JEDEC      |                            |      |             |      |



|   |                           |                            |
|---|---------------------------|----------------------------|
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| TITLE:<br><br>NI-400S-240                               | DOCUMENT NO: 98ASA10732D  | REV: A                     |
|   | CASE NUMBER: 465J-02      | 09 MAY 2006                |
|   | STANDARD: NON-JEDEC       |                            |

NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DIMENSION H IS MEASURED .030 (0.762) AWAY FROM PACKAGE BODY

STYLE 1:

- PIN 1 - DRAIN
- 2 - GATE
- 3 - SOURCE

STYLE 2:

- PIN 1 - GATE
- 2 - DRAIN
- 3 - SOURCE

| DIM   | INCH  |       | MILLIMETER                |       | DIM                      | INCH                       |     | MILLIMETER  |       |
|---|-------|-------|---------------------------|-------|--------------------------|----------------------------|-----|-------------|-------|
|   | MIN   | MAX   | MIN                       | MAX   |                          | MIN                        | MAX | MIN         | MAX   |
| A   | .395  | .405  | 10.03                     | 10.29 | aaa                      | .005                       |     |             | 0.127 |
| B   | .380  | .390  | 9.65                      | 9.91  | bbb                      | .010                       |     |             | 0.254 |
| C   | .125  | .163  | 3.18                      | 4.14  | ccc                      | .015                       |     |             | 0.381 |
| D   | .275  | .285  | 6.98                      | 7.24  |                          |                            |     |             |       |
| E   | .035  | .045  | 0.89                      | 1.14  |                          |                            |     |             |       |
| F   | .004  | .006  | 0.10                      | 0.15  |                          |                            |     |             |       |
| H   | .057  | .067  | 1.45                      | 1.70  |                          |                            |     |             |       |
| K   | .0995 | .1295 | 2.53                      | 3.29  |                          |                            |     |             |       |
| M   | .395  | .405  | 10.03                     | 10.29 |                          |                            |     |             |       |
| N   | .385  | .395  | 9.78                      | 10.03 |                          |                            |     |             |       |
| R   | .355  | .365  | 9.02                      | 9.27  |                          |                            |     |             |       |
| S   | .365  | .375  | 9.27                      | 9.53  |                          |                            |     |             |       |
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| TITLE:<br><br>NI-400S-240                               |       |       |                           |       | DOCUMENT NO: 98ASA10732D |                            |     | REV: A      |       |
|   |       |       |                           |       | CASE NUMBER: 465J-02     |                            |     | 09 MAY 2006 |       |
|   |       |       |                           |       | STANDARD: NON-JEDEC      |                            |     |             |       |

## PRODUCT DOCUMENTATION

Refer to the following documents to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

## REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date      | Description   |
|----------|-----------|---|
| 0        | Aug. 2007 | <ul style="list-style-type: none"><li>• Initial Release of Data Sheet</li></ul> |

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